

BSC0502NSIATMA1

BSC0502NSIATMA1 Information

wyourmersener.com	 BSC0502NSIATMA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 30V 26A TDSON-8 8-PowerTDFN For the pricing/inventory/lead time, please contact us	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BSC0502NSIATMA1 Specifications

Manufacturer Part Number	BSC0502NSIATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	26A (Ta), 100A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	26nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	1600pF @ 15V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	2.5W (Ta), 43W (Tc)
Rds On (Max) @ Id, Vgs	2.3 mOhm @ 30A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TDSON-8
Package / Case	8-PowerTDFN
	Report errors?

BSC0502NSIATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

BSC0502NSIATMA1 Payment Methods





If you have any question about BSC0502NSIATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com